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FDG332PZ

P-Channel PowerTrench® MOSFET

-20V, -2.6A, 97mΩ

Features

- Max $r_{DS(on)}$ = 95mΩ at $V_{GS} = -4.5V$, $I_D = -2.6A$
- Max $r_{DS(on)}$ = 115mΩ at $V_{GS} = -2.5V$, $I_D = -2.2A$
- Max $r_{DS(on)}$ = 160mΩ at $V_{GS} = -1.8V$, $I_D = -1.9A$
- Max $r_{DS(on)}$ = 330mΩ at $V_{GS} = -1.5V$, $I_D = -1.0A$
- Very low level gate drive requirements allowing operation in 1.5V circuits
- Very small package outline SC70-6
- RoHS Compliant

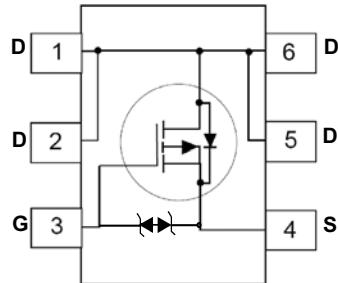
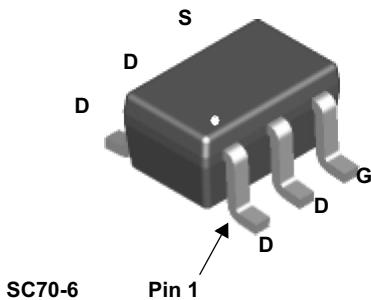


General Description

This P-Channel MOSFET uses Fairchild's advanced low voltage PowerTrench® process. It has been optimized for battery power management applications.

Applications

- Battery management
- Load switch



MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DS}	Drain to Source Voltage	-20	V
V_{GS}	Gate to Source Voltage	± 8	V
I_D	Drain Current -Continuous	-2.6	A
	-Pulsed	-9	
P_D	Power Dissipation (Note 1a)	0.75	W
	Power Dissipation (Note 1b)	0.48	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Single operation (Note 1a)	170	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Single operation (Note 1b)	260	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.2P	FDG332PZ	SC70-6	7"	8 mm	3000 units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = -250\mu\text{A}$, $V_{GS} = 0\text{V}$	-20			V
$\frac{\Delta \text{BV}_{\text{DSS}}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\mu\text{A}$, referenced to 25°C		-13		mV°C
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16\text{V}$, $V_{GS} = 0\text{V}$			-1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8\text{V}$, $V_{DS} = 0\text{V}$			± 10	μA

On Characteristics

$V_{GS(\text{th})}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = -250\mu\text{A}$	-0.4	-0.7	-1.5	V
$\frac{\Delta V_{GS(\text{th})}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\mu\text{A}$, referenced to 25°C		2.5		mV°C
$r_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = -4.5\text{V}$, $I_D = -2.6\text{A}$	73	95		$\text{m}\Omega$
		$V_{GS} = -2.5\text{V}$, $I_D = -2.2\text{A}$	90	115		
		$V_{GS} = -1.8\text{V}$, $I_D = -1.9\text{A}$	117	160		
		$V_{GS} = -1.5\text{V}$, $I_D = -1.0\text{A}$	147	330		
		$V_{GS} = -4.5\text{V}$, $I_D = -2.6\text{A}$, $T_J = 125^\circ\text{C}$	100	133		
g_{FS}	Forward Transconductance	$V_{DD} = -5\text{V}$, $I_D = -2.6\text{A}$	9			S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = -10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$		420	560	pF
C_{oss}	Output Capacitance			85	115	pF
C_{rss}	Reverse Transfer Capacitance			75	115	pF

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -10\text{V}$, $I_D = -2.6\text{A}$, $V_{GS} = -4.5\text{V}$, $R_{\text{GEN}} = 6\Omega$		5.2	10	ns
t_r	Rise Time			4.8	10	ns
$t_{d(off)}$	Turn-Off Delay Time			59	95	ns
t_f	Fall Time			28	45	ns
Q_g	Total Gate Charge	$V_{GS} = -4.5\text{V}$, $V_{DD} = -10\text{V}$, $I_D = -2.6\text{A}$		7.6	10.8	nC
Q_{gs}	Gate to Source Charge			0.9		nC
Q_{gd}	Gate to Drain "Miller" Charge			1.9		nC

Drain-Source Diode Characteristics and Maximum Ratings

I_s	Maximum Continuous Drain-Source Diode Forward Current			-0.6	A	
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{V}$, $I_s = -0.6\text{A}$ (Note 2)		-0.7	-1.2	V
t_{rr}	Reverse Recovery Time			28	45	ns
Q_{rr}	Reverse Recovery Charge	$I_F = 2.6\text{A}$, $di/dt = 100\text{A}/\mu\text{s}$		8	13	nC

Notes:

1. R_{QJA} is determined with the device mounted on a 1in^2 pad 2 oz copper pad on a 1.5×1.5 in. board of FR-4 material. R_{QJC} is guaranteed by design while R_{QCA} is determined by the user's board design.



a. $170^\circ\text{C}/\text{W}$ when mounted on
a 1in^2 pad of 2 oz copper .



b. $260^\circ\text{C}/\text{W}$ when mounted on
a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width $< 300\mu\text{s}$, Duty cycle $< 2.0\%$.

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

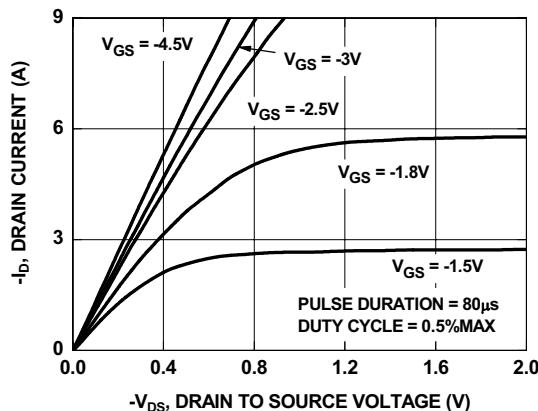


Figure 1. On-Region Characteristics

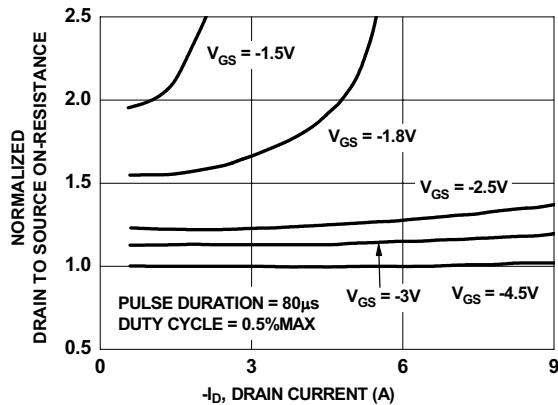


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

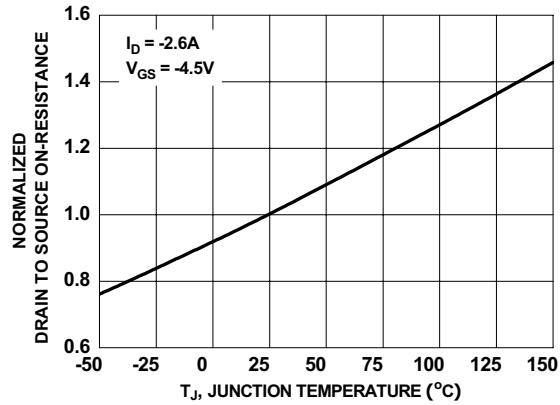


Figure 3. Normalized On-Resistance vs Junction Temperature

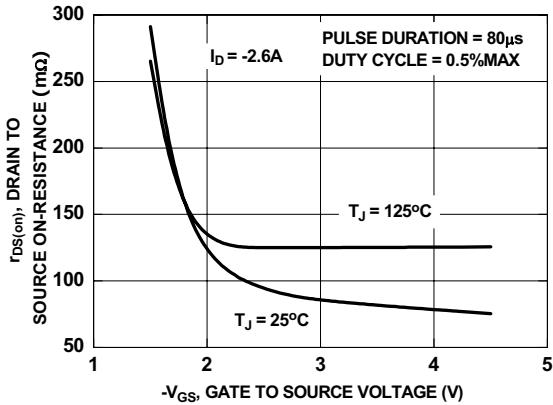


Figure 4. On-Resistance vs Gate to Source Voltage

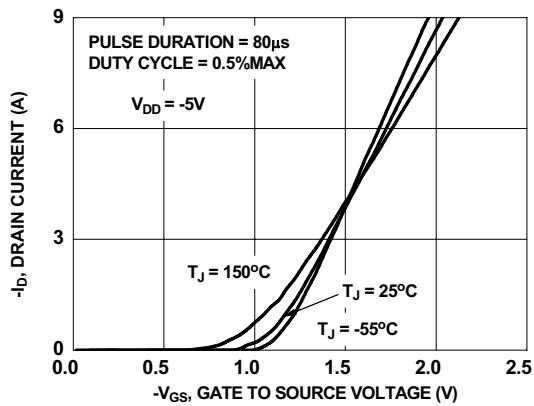


Figure 5. Transfer Characteristics

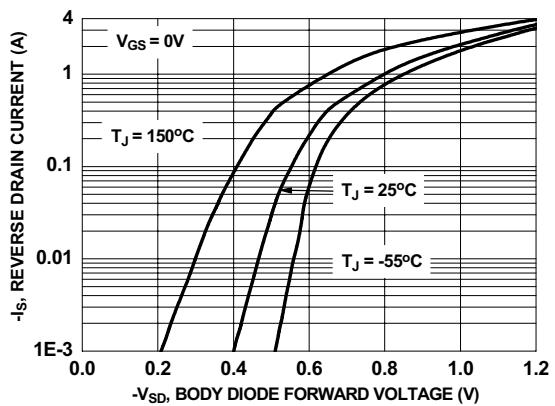


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

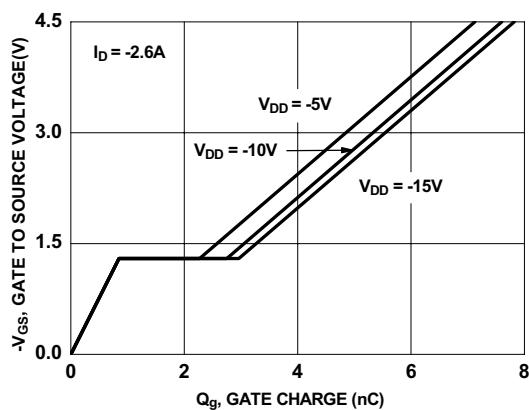


Figure 7. Gate Charge Characteristics

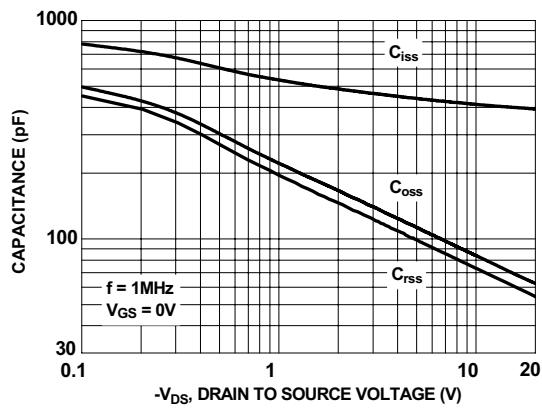


Figure 8. Capacitance vs Drain to Source Voltage

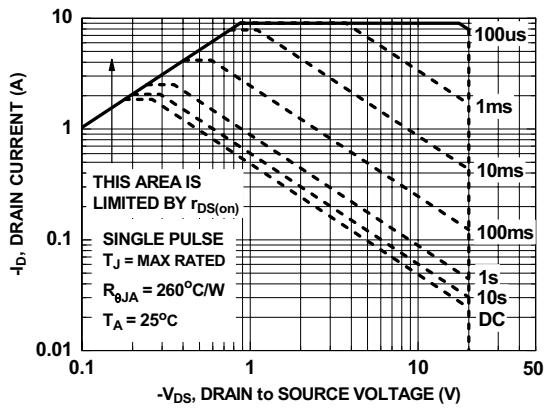


Figure 9. Forward Bias Safe Operating Area

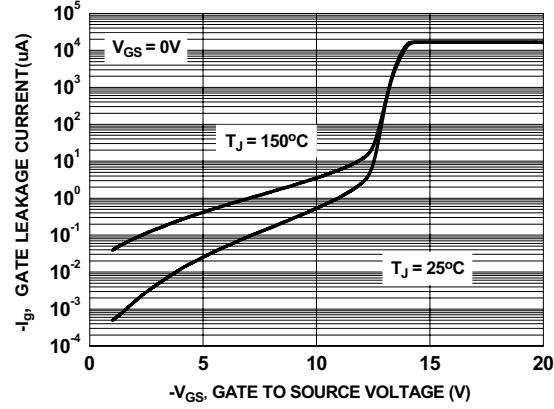


Figure 10. Gate Leakage Current vs Gate to Source Voltage

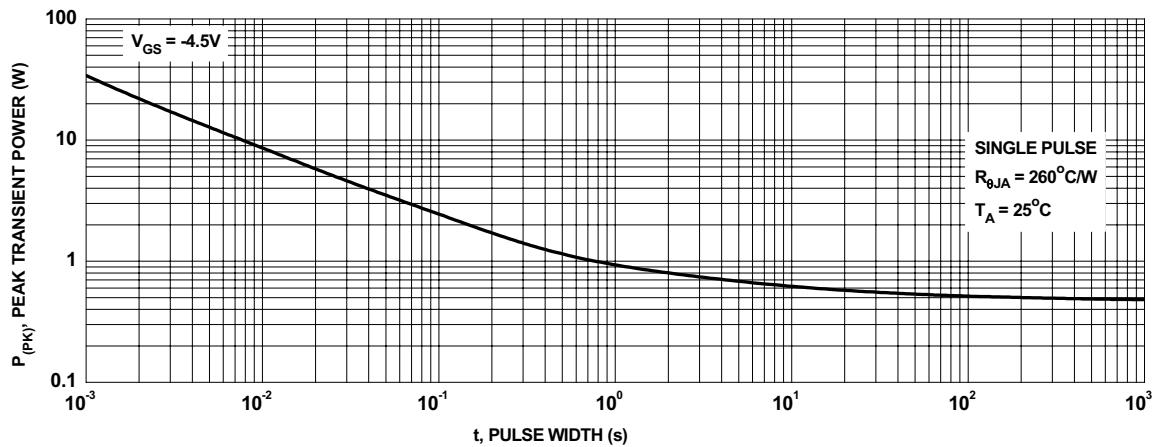


Figure 11. Transient Thermal Response Curve

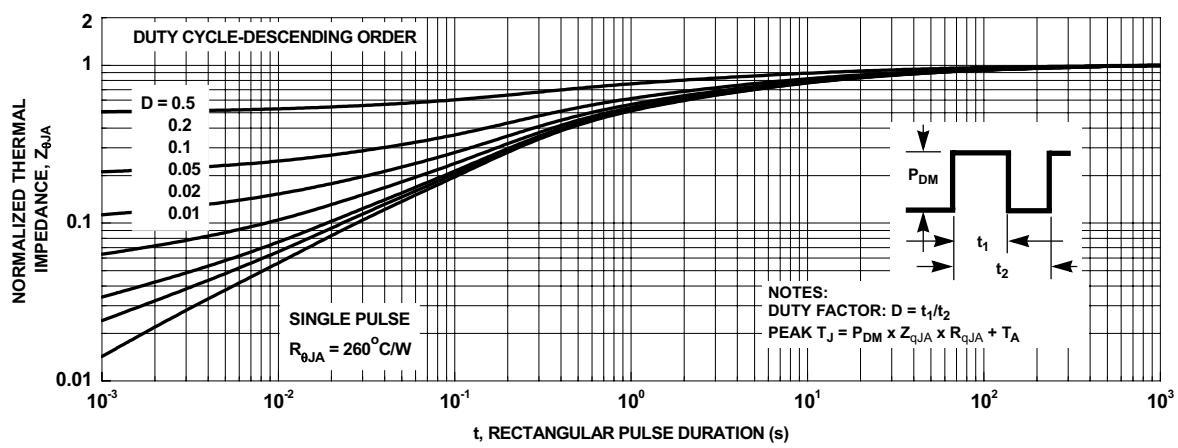
Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Figure 12. Transient Thermal Response Curve



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